



### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub> (@ T <sub>J</sub> Max) (Note 7)	Rds(on)	I <sub>D</sub> T <sub>C</sub> = +25°C
1000V	$2.2\Omega@V_{GS} = 10V$	6A

### Description

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

### **Applications**

- Motor controls
- Backlighting
- DC-DC converters
- Power management functions

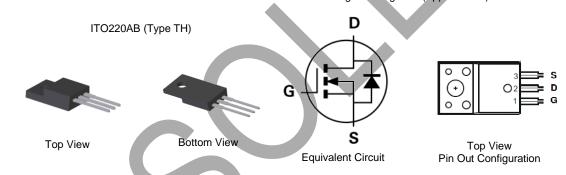
### Features

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- Low Input Capacitance
- High BV<sub>DSS</sub> Rating for Power Application
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

## **Mechanical Data**

- Package: ITO220AB
- Package Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed Over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram Below
- Weight: 1.85 grams (Approximate)



# Ordering Information (Note 4)

	Part Number	Package	Packing		
Part Number		Гаскауе	Qty.	Carrier	
	DMN90H2D2HCTI	ITO220AB (Type TH)	50 Pieces	Tube	
Notes:	1. EU Directive 2002/95/EC (Rol	HS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) com	npliant. All applicable RoHS exemp	tions applied.	

ED Directive 2002/95/EC (ROHS), 2011/b5/EU (ROHS 2) & 2015/863/EU (ROHS 3) compliant. All applicable ROHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



) | |=Manufacturer's Marking 90H2D2H = Product Type Marking Code YYWW = Date Code Marking YY or <u>YY</u> = Last Two Digits of Year (ex: 20 = 2020) WW or <u>WW</u>= Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		Vdss	900	V
Gate-Source Voltage		Vgss	±30	V
Continuous Drain Current (Notes 5) V <sub>GS</sub> = 10V (Note 6)	Tc = +25°C Tc = +100°C	Iр	6 4	A
Pulsed Drain Current		IDM	24	A
Avalanche Current, L = 60mH (Note 7)		las	3.5	A
Avalanche Energy, L = 60mH (Note 7)		Eas	360	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Max		Unit
Power Dissipation (Note 5)	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	PD	40 14		w
Thermal Resistance, Junction to Case (Note 5)	Tc = +25°C	Rejc	3.6		°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	)	°C

### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

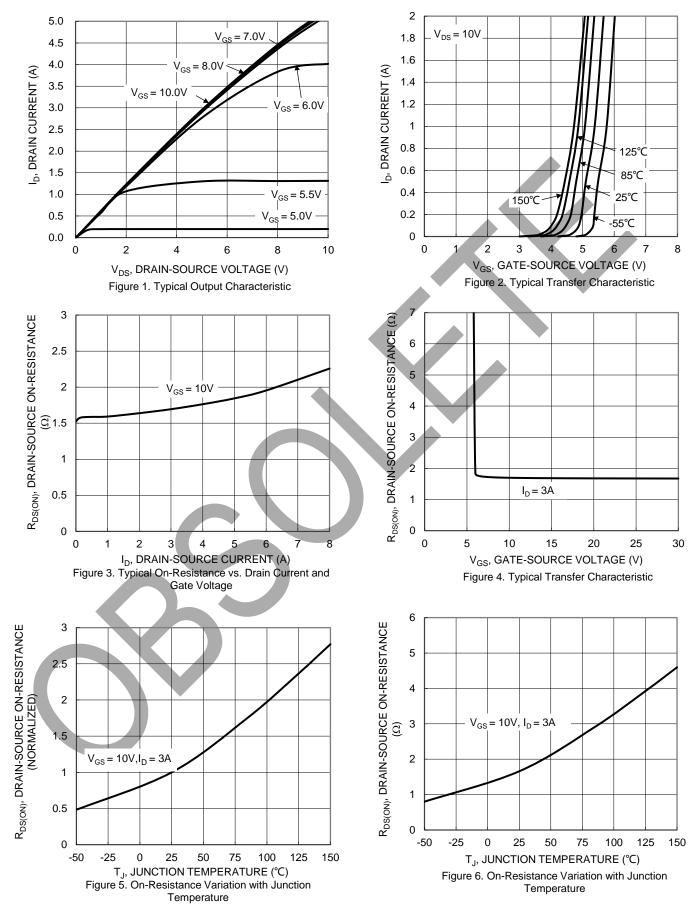
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	900	—	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS		—	1	μA	V <sub>DS</sub> = 900V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	lgss	-		100	nA	$V_{GS} = \pm 30V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)				·		•	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	3	4	5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	—	1.7	2.2	Ω	$V_{GS} = 10V, I_D = 3A$	
Diode Forward Voltage	Vsd	_	0.85	1.2	V	$V_{GS} = 0V$ , $I_S = 6A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	1487	_		V <sub>DS</sub> = 25V, f = 1MHz,	
Output Capacitance	Coss	_	113	—	pF	$V_{\rm DS} = 25$ V, $T = TWHZ$ , V <sub>GS</sub> = 0V	
Reverse Transfer Capacitance	Crss	_	1	_		VGS = 0V	
Gate Resistance	Rg	_	4.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	20.3	_		V( 700)/ L 0A	
Gate-Source Charge	Qgs	_	6.4	_	nC	$V_{DD} = 720V, I_D = 6A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Qgd	_	6.1	_		VGS = 10V	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	39	_		$V_{DD} = 450V, V_{GS} = 10V,$ $R_g = 25\Omega, ID = 6A$	
Turn-On Rise Time	t <sub>R</sub>	_	49	_	-		
Turn-Off Delay Time	tD(OFF)	—	51	—	ns		
Turn-Off Fall Time	tF		31	_	1		
Body Diode Reverse Recovery Time	t <sub>RR</sub>	—	607	—	ns		
Body Diode Reverse Recovery Charge	QRR	—	8.1	—	μC	$-I_F = 6A, dI/dt = 100A/\mu s$	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Drain current limited by maximum junction temperature. Notes:

Guaranteed by design. Not subject to production testing.
Short duration pulse test used to minimize self-heating effect.



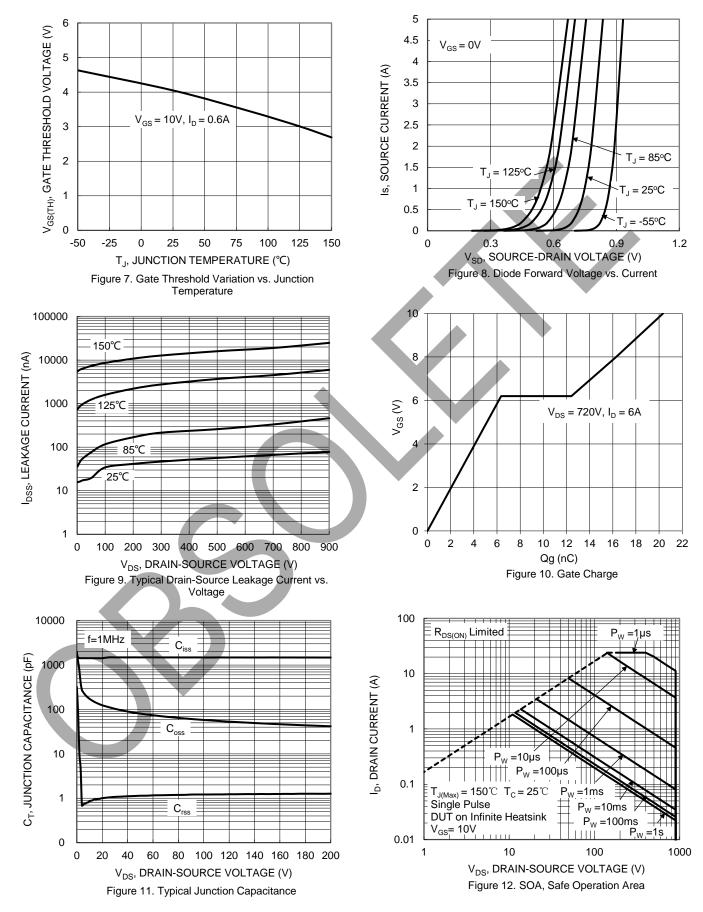
## DMN90H2D2HCTI



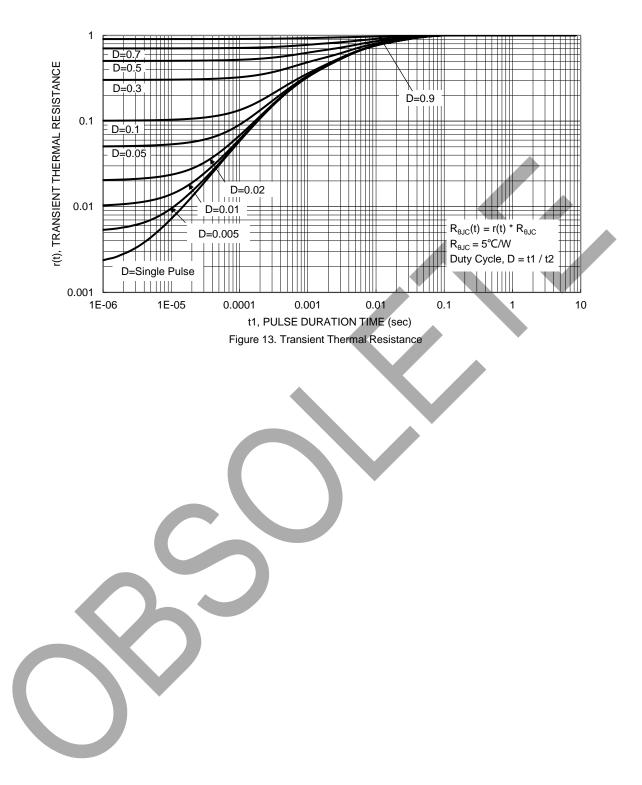
DMN90H2D2HCTI Document number: DS38826 Rev. 6 - 4



# DMN90H2D2HCTI





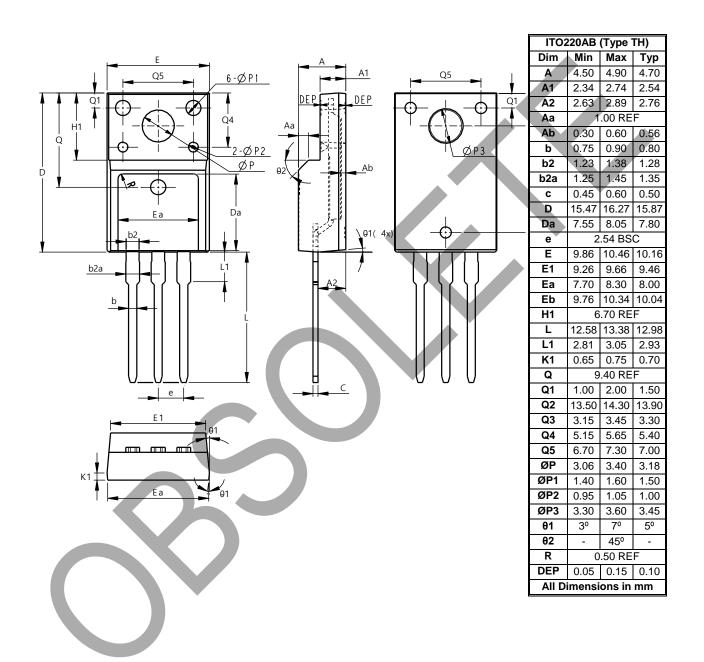




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

ITO220AB (Type TH)





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